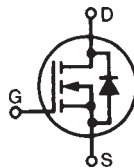


# PolarHT™ HiPerFET Power MOSFET

**IXFK 120N25P**  
**IXFX 120N25P**

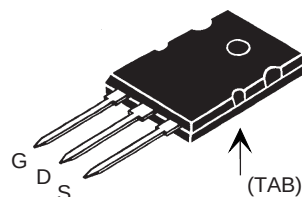
N-Channel Enhancement Mode  
Fast Intrinsic Diode  
Avalanche Rated

$$\begin{aligned} V_{DSS} &= 250 \text{ V} \\ I_{D25} &= 120 \text{ A} \\ R_{DS(on)} &\leq 24 \text{ m}\Omega \\ t_{rr} &\leq 200 \text{ ns} \end{aligned}$$

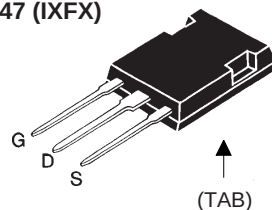


| Symbol       | Test Conditions                                                                                                                         | Maximum Ratings |                  |
|--------------|-----------------------------------------------------------------------------------------------------------------------------------------|-----------------|------------------|
| $V_{DSS}$    | $T_J = 25^\circ\text{C}$ to $175^\circ\text{C}$                                                                                         | 250             | V                |
| $V_{DGR}$    | $T_J = 25^\circ\text{C}$ to $175^\circ\text{C}$ ; $R_{GS} = 1 \text{ M}\Omega$                                                          | 250             | V                |
| $V_{GS}$     | Continuous                                                                                                                              | $\pm 20$        | V                |
| $V_{GSM}$    | Transient                                                                                                                               | $\pm 30$        | V                |
| $I_{D25}$    | $T_C = 25^\circ\text{C}$                                                                                                                | 120             | A                |
| $I_{D(RMS)}$ | External lead current limit                                                                                                             | 75              | A                |
| $I_{DM}$     | $T_C = 25^\circ\text{C}$ , pulse width limited by $T_{JM}$                                                                              | 300             | A                |
| $I_{AR}$     | $T_C = 25^\circ\text{C}$                                                                                                                | 60              | A                |
| $E_{AR}$     | $T_C = 25^\circ\text{C}$                                                                                                                | 60              | mJ               |
| $E_{AS}$     | $T_C = 25^\circ\text{C}$                                                                                                                | 2.5             | J                |
| $dv/dt$      | $I_S \leq I_{DM}$ , $di/dt \leq 100 \text{ A}/\mu\text{s}$ , $V_{DD} \leq V_{DSS}$ ,<br>$T_J \leq 150^\circ\text{C}$ , $R_G = 4 \Omega$ | 10              | V/ns             |
| $P_D$        | $T_C = 25^\circ\text{C}$                                                                                                                | 700             | W                |
| $T_J$        |                                                                                                                                         | -55 ... +175    | $^\circ\text{C}$ |
| $T_{JM}$     |                                                                                                                                         | 175             | $^\circ\text{C}$ |
| $T_{stg}$    |                                                                                                                                         | -55 ... +150    | $^\circ\text{C}$ |
| $T_L$        | 1.6 mm (0.062 in.) from case for 10 s                                                                                                   | 300             | $^\circ\text{C}$ |
| $T_{SOLD}$   | Plastic body for 10 s                                                                                                                   | 260             | $^\circ\text{C}$ |
| $M_d$        | Mounting torque                                                                                                                         | 1.13/10         | Nm/lb.in.        |
| Weight       | TO-264                                                                                                                                  | 10              | g                |
|              | PLUS247                                                                                                                                 | 6               | g                |

TO-264 (IXFK)



PLUS247 (IXFX)



G = Gate      D = Drain  
S = Source    TAB = Drain

## Features

- International standard packages
- Unclamped Inductive Switching (UIS) rated
- Low package inductance
  - easy to drive and to protect

## Advantages

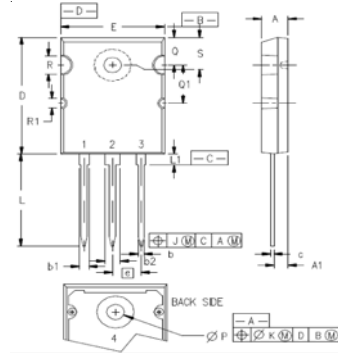
- Easy to mount
- Space savings
- High power density

| Symbol       | Test Conditions<br>( $T_J = 25^\circ\text{C}$ , unless otherwise specified)                                      | Characteristic Values |      |                      |
|--------------|------------------------------------------------------------------------------------------------------------------|-----------------------|------|----------------------|
|              |                                                                                                                  | Min.                  | Typ. | Max.                 |
| $BV_{DSS}$   | $V_{GS} = 0 \text{ V}$ , $I_D = 250 \mu\text{A}$                                                                 | 250                   |      | V                    |
| $V_{GS(th)}$ | $V_{DS} = V_{GS}$ , $I_D = 4 \text{ mA}$                                                                         | 2.5                   |      | 5.0 V                |
| $I_{GSS}$    | $V_{GS} = \pm 20 \text{ V}$ , $V_{DS} = 0 \text{ V}$                                                             |                       |      | $\pm 200 \text{ nA}$ |
| $I_{DSS}$    | $V_{DS} = V_{DSS}$<br>$V_{GS} = 0 \text{ V}$<br>$T_J = 125^\circ\text{C}$                                        |                       |      | 25 $\mu\text{A}$     |
|              |                                                                                                                  |                       |      | 250 $\mu\text{A}$    |
| $R_{DS(on)}$ | $V_{GS} = 10 \text{ V}$ , $I_D = 0.5 I_{D25}$<br>Pulse test, $t \leq 300 \mu\text{s}$ , duty cycle $d \leq 2 \%$ | 19                    | 24   | $\text{m}\Omega$     |

| Symbol       | Test Conditions                                                                                   | Characteristic Values<br>( $T_J = 25^\circ\text{C}$ , unless otherwise specified) |      |                        |
|--------------|---------------------------------------------------------------------------------------------------|-----------------------------------------------------------------------------------|------|------------------------|
|              |                                                                                                   | Min.                                                                              | Typ. | Max.                   |
| $g_{fs}$     | $V_{DS} = 10\text{ V}; I_D = 0.5 I_{D25}$ , pulse test                                            | 45                                                                                | 70   | S                      |
| $C_{iss}$    | $V_{GS} = 0\text{ V}, V_{DS} = 25\text{ V}, f = 1\text{ MHz}$                                     |                                                                                   | 8000 | pF                     |
| $C_{oss}$    |                                                                                                   |                                                                                   | 1300 | pF                     |
| $C_{rss}$    |                                                                                                   |                                                                                   | 220  | pF                     |
| $t_{d(on)}$  | $V_{GS} = 10\text{ V}, V_{DS} = 0.5 V_{DSS}, I_D = 60\text{ A}$<br>$R_G = 3.3\ \Omega$ (External) |                                                                                   | 30   | ns                     |
| $t_r$        |                                                                                                   |                                                                                   | 33   | ns                     |
| $t_{d(off)}$ |                                                                                                   |                                                                                   | 130  | ns                     |
| $t_f$        |                                                                                                   |                                                                                   | 33   | ns                     |
| $Q_{g(on)}$  | $V_{GS} = 10\text{ V}, V_{DS} = 0.5 V_{DSS}, I_D = 0.5 I_{D25}$                                   |                                                                                   | 185  | nC                     |
| $Q_{gs}$     |                                                                                                   |                                                                                   | 50   | nC                     |
| $Q_{gd}$     |                                                                                                   |                                                                                   | 80   | nC                     |
| $R_{thJC}$   |                                                                                                   | 0.15                                                                              |      | $0.18^\circ\text{C/W}$ |
| $R_{thCK}$   |                                                                                                   |                                                                                   |      | $^\circ\text{C/W}$     |

| Source-Drain Diode |                                                                                                       | Characteristic Values<br>( $T_J = 25^\circ\text{C}$ , unless otherwise specified) |      |               |
|--------------------|-------------------------------------------------------------------------------------------------------|-----------------------------------------------------------------------------------|------|---------------|
| Symbol             | Test Conditions                                                                                       | Min.                                                                              | Typ. | Max.          |
| $I_S$              | $V_{GS} = 0\text{ V}$                                                                                 |                                                                                   |      | 120 A         |
| $I_{SM}$           | Repetitive                                                                                            |                                                                                   |      | 300 A         |
| $V_{SD}$           | $I_F = I_S, V_{GS} = 0\text{ V}$ ,<br>Pulse test, $t \leq 300\ \mu\text{s}$ , duty cycle $d \leq 2\%$ |                                                                                   |      | 1.5 V         |
| $t_{rr}$           | $I_F = 25\text{ A}; -di/dt = 100\text{ A}/\mu\text{s}; V_R = 100\text{ V}$<br>$V_{GS} = 0\text{ V}$   |                                                                                   | 0.8  | 200 ns        |
| $Q_{RM}$           |                                                                                                       |                                                                                   |      | $\mu\text{C}$ |
| $I_{RM}$           |                                                                                                       |                                                                                   |      | A             |

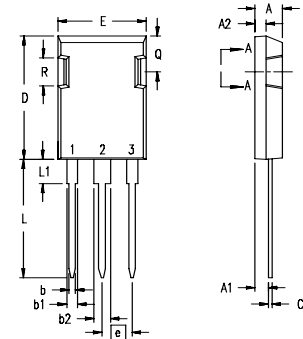
### TO-264 (IXFK) Outline



- 1 - GATE  
2, 4 - DRAIN (COLLECTOR)  
3 - SOURCE (EMITTER)

| SYM | INCHES   |       | MILLIMETERS |       |
|-----|----------|-------|-------------|-------|
|     | MIN      | MAX   | MIN         | MAX   |
| A   | .185     | .209  | 4.70        | 5.31  |
| A1  | .102     | .118  | 2.59        | 3.00  |
| b   | .037     | .055  | 0.94        | 1.40  |
| b1  | .087     | .102  | 2.21        | 2.59  |
| b2  | .110     | .126  | 2.79        | 3.20  |
| c   | .017     | .029  | 0.43        | 0.74  |
| D   | 1.007    | 1.047 | 25.58       | 26.59 |
| E   | .760     | .799  | 19.30       | 20.29 |
| e   | .215 BSC |       | 5.46 BSC    |       |
| J   | .000     | .010  | 0.00        | 0.25  |
| K   | .000     | .010  | 0.00        | 0.25  |
| L   | .779     | .842  | 19.79       | 21.39 |
| L1  | .087     | .102  | 2.21        | 2.59  |
| ØP  | .122     | .138  | 3.10        | 3.51  |
| Q   | .240     | .256  | 6.10        | 6.50  |
| Q1  | .330     | .346  | 8.38        | 8.79  |
| ØR  | .155     | .187  | 3.94        | 4.75  |
| ØR1 | .085     | .093  | 2.16        | 2.36  |
| S   | .243     | .253  | 6.17        | 6.43  |

### PLUS 247™ (IXFX) Outline



- Terminals: 1 - Gate  
2 - Drain (Collector)  
3 - Source (Emitter)  
4 - Drain (Collector)

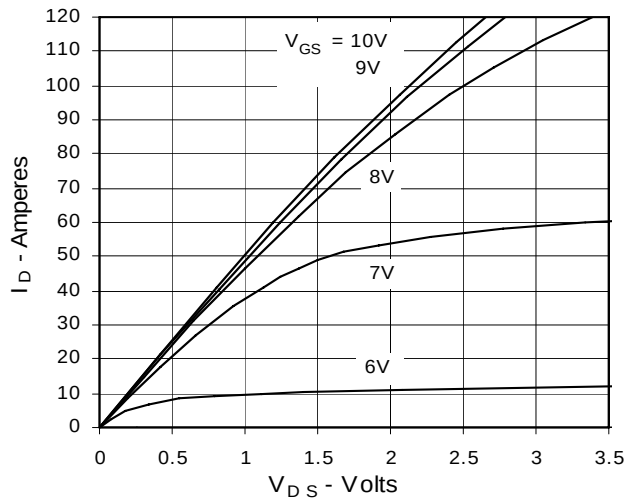
| Dim.           | Millimeter |       | Inches   |       |
|----------------|------------|-------|----------|-------|
|                | Min.       | Max.  | Min.     | Max.  |
| A              | 4.83       | 5.21  | .190     | .205  |
| A <sub>1</sub> | 2.29       | 2.54  | .090     | .100  |
| A <sub>2</sub> | 1.91       | 2.16  | .075     | .085  |
| b              | 1.14       | 1.40  | .045     | .055  |
| b <sub>1</sub> | 1.91       | 2.13  | .075     | .084  |
| b <sub>2</sub> | 2.92       | 3.12  | .115     | .123  |
| C              | 0.61       | 0.80  | .024     | .031  |
| D              | 20.80      | 21.34 | .819     | .840  |
| E              | 15.75      | 16.13 | .620     | .635  |
| e              | 5.45 BSC   |       | .215 BSC |       |
| L              | 19.81      | 20.32 | .780     | .800  |
| L1             | 3.81       | 4.32  | .150     | .170  |
| Q              | 5.59       | 6.20  | .220     | 0.244 |
| R              | 4.32       | 4.83  | .170     | .190  |

IXYS reserves the right to change limits, test conditions, and dimensions.

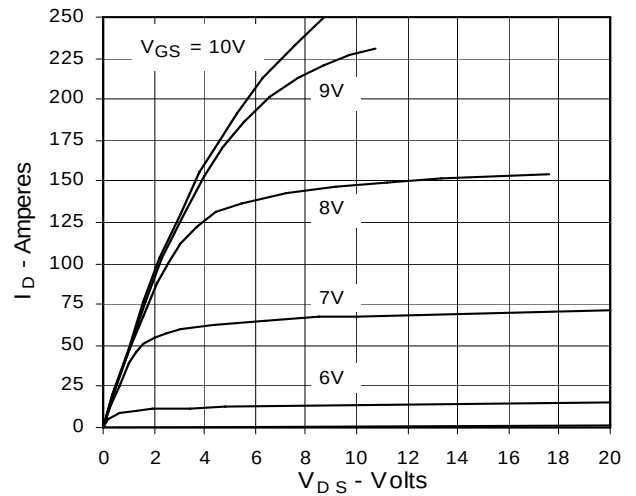
IXYS MOSFETs and IGBTs are covered by one or more of the following U.S. patents:

|           |           |           |           |              |              |              |              |
|-----------|-----------|-----------|-----------|--------------|--------------|--------------|--------------|
| 4,835,592 | 4,931,844 | 5,049,961 | 5,237,481 | 6,162,665    | 6,404,065 B1 | 6,683,344    | 6,727,585    |
| 4,850,072 | 5,017,508 | 5,063,307 | 5,381,025 | 6,259,123 B1 | 6,534,343    | 6,710,405 B2 | 6,759,692    |
| 4,881,106 | 5,034,796 | 5,187,117 | 5,486,715 | 6,306,728 B1 | 6,583,505    | 6,710,463    | 6,771,478 B2 |

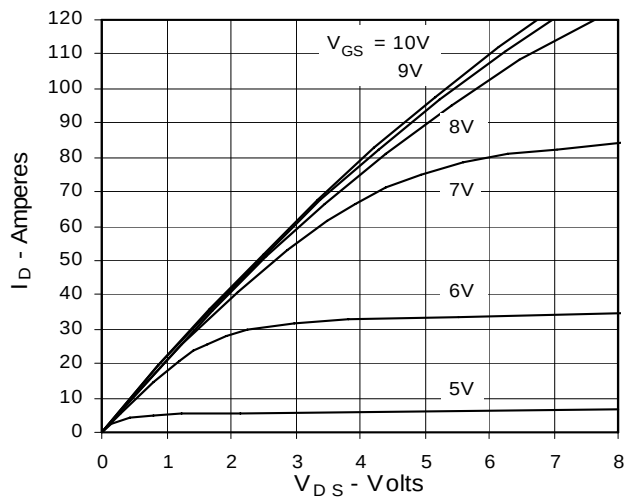
**Fig. 1. Output Characteristics**  
**@ 25°C**



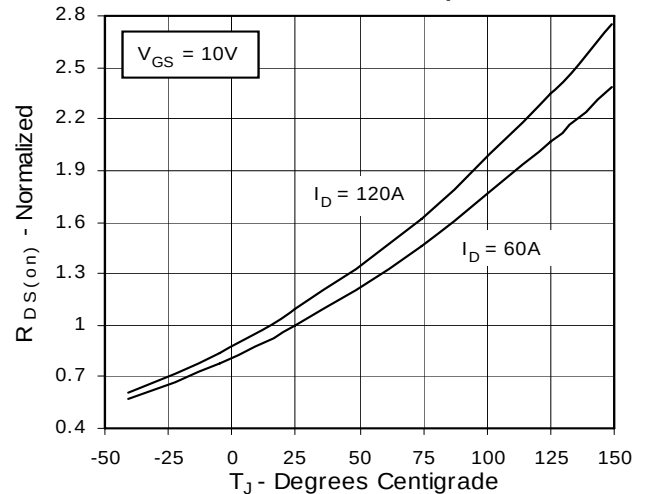
**Fig. 2. Extended Output Characteristics**  
**@ 25°C**



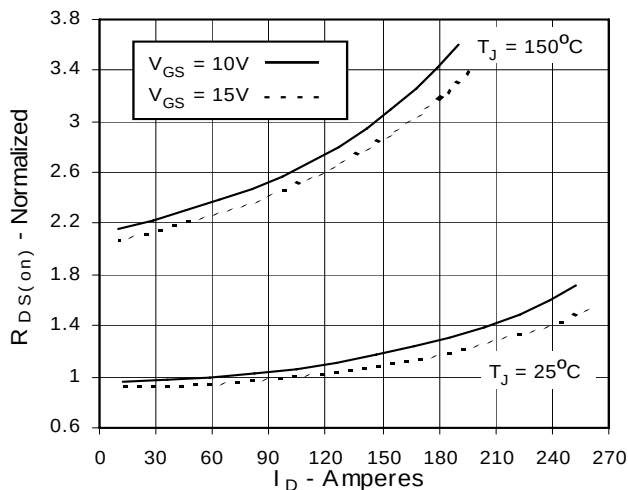
**Fig. 3. Output Characteristics**  
**@ 150°C**



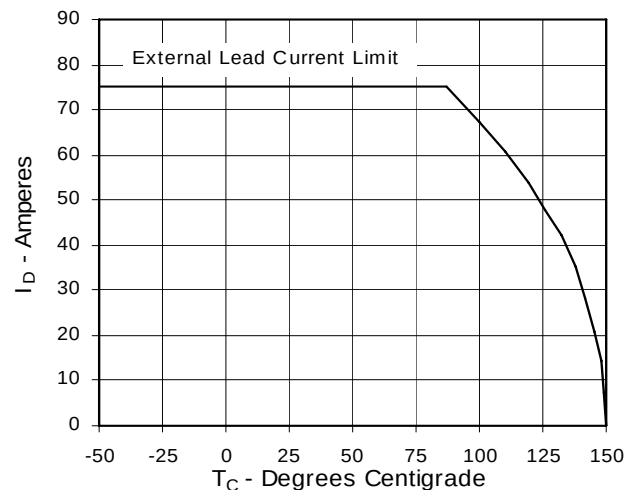
**Fig. 4.  $R_{DS(on)}$  Normalized to 0.5  $I_{D25}$**   
**Value vs. Junction Temperature**



**Fig. 5.  $R_{DS(on)}$  Normalized to 0.5  $I_{D25}$**   
**Value vs. Drain Current**



**Fig. 6. Drain Current vs. Case Temperature**



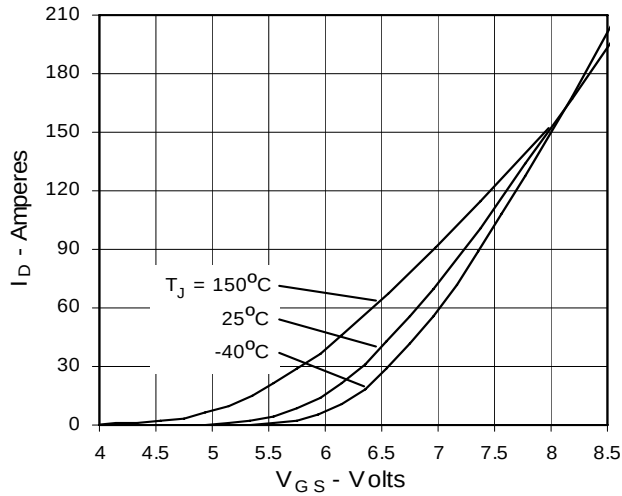
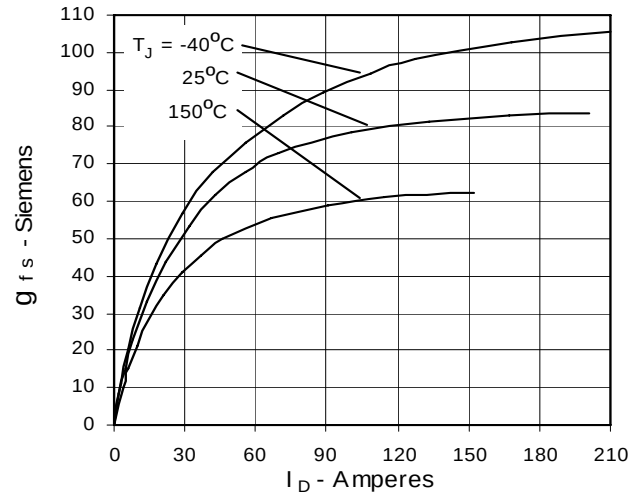
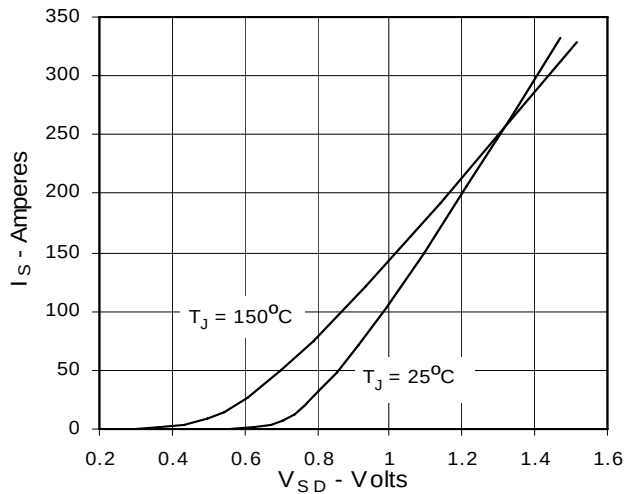
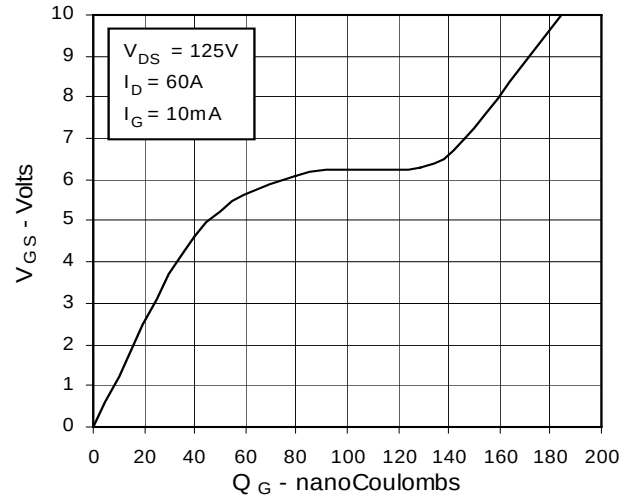
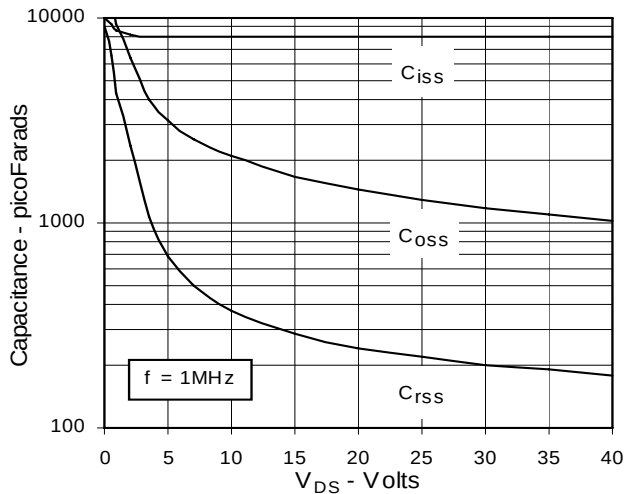
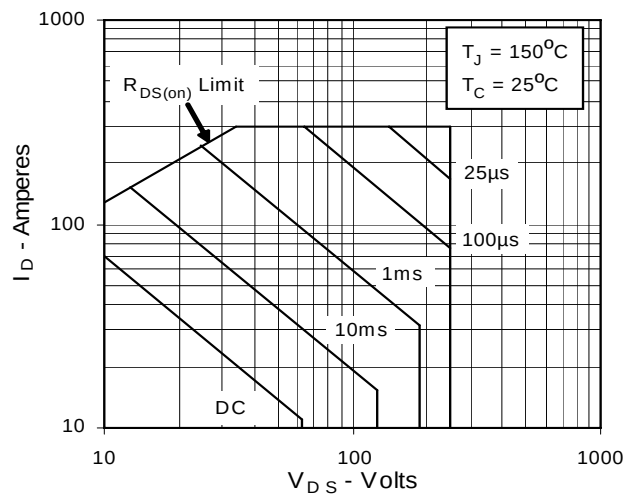
**Fig. 7. Input Admittance**

**Fig. 8. Transconductance**

**Fig. 9. Source Current vs. Source-To-Drain Voltage**

**Fig. 10. Gate Charge**

**Fig. 11. Capacitance**

**Fig. 12. Forward-Bias Safe Operating Area**


Fig. 13. Maximum Transient Thermal Resistance

